## 1. General description

NPN high power bipolar transistor in a power DPAK, TO-252 (SOT428C) Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- High thermal power dissipation capability
- High energy efficiency due to less heat generation
- · Electrically similar to popular MJD2873 series
- Low collector emitter saturation voltage
- Fast switching speeds

## 3. Applications

- Power management
- Load switch
- · Linear mode voltage regulator
- · Constant current drive backlighting application
- Motor drive
- · Relay replacement

### 4. Quick reference data

Table 1. Quick reference data

| Symbol           | Parameter                 | Conditions  | Min | Тур | Max | Unit |
|------------------|---------------------------|---|-----|-----|-----|------|
| V <sub>CEO</sub> | collector-emitter voltage | open base   | -   | -   | 50  | V    |
| I <sub>C</sub>   | collector current         |   | -   | -   | 2   | Α    |
| I <sub>CM</sub>  | peak collector current    | single pulse; t <sub>p</sub> ≤ 1 ms   | -   | -   | 3   | А    |
| h <sub>FE</sub>  | DC current gain           | $V_{CE}$ = 2 V; $I_{C}$ = 0.5 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C        | 120 | -   | 360 |      |
|                  |                           | $V_{CE}$ = 2 V; $I_{C}$ = 2 A; pulsed; $t_{p} \le 300 \mu s$ ;<br>δ ≤ 0.02; $T_{amb}$ = 25 °C | 40  | -   | -   |      |



#### 50 V, 2 A NPN high power bipolar transistor

# 5. Pinning information

#### **Table 2. Pinning information**

| Pin | Symbol | Description                           | Simplified outline | Graphic symbol |
|-----|--------|---------------------------------------|--------------------|----------------|
| 1   | В      | base                                  | mb                 | Ë              |
| 2   | С      | collector                             |                    | в -[*          |
| 3   | Е      | emitter                               |                    | C; mb          |
| mb  | С      | mounting base; connected to collector | DPAK (SOT428C)     | aaa-029889     |

# 6. Ordering information

#### **Table 3. Ordering information**

| Type number | Package |   |         |  |  |
|-------------|---------|---|---------|--|--|
|             | Name    | Description   | Version |  |  |
| MJD2873     | DPAK    | Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped) | SOT428C |  |  |

# 7. Marking

#### Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| MJD2873     | MJD2873      |

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC601134).

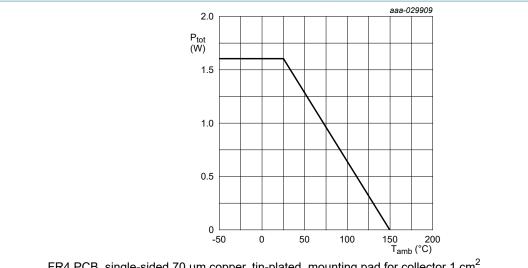
| Symbol           | Parameter                 | Conditions                          |     | Min | Max | Unit |
|------------------|---------------------------|-------------------------------------|-----|-----|-----|------|
| V <sub>CEO</sub> | collector-emitter voltage | open base                           |     | -   | 50  | V    |
| V <sub>EBO</sub> | emitter-base voltage      | open collector                      |     | -   | 6   | V    |
| I <sub>C</sub>   | collector current         |                                     |     | -   | 2   | А    |
| I <sub>CM</sub>  | peak collector current    | single pulse; t <sub>p</sub> ≤ 1 ms |     | -   | 3   | А    |
| P <sub>tot</sub> | total power dissipation   | T <sub>mb</sub> ≤ 25 °C             | [1] | -   | 15  | W    |
|                  |                           | T <sub>amb</sub> ≤ 25 °C            | [2] | -   | 1.6 | W    |
| Tj               | junction temperature      |                                     |     | -   | 150 | °C   |
| T <sub>amb</sub> | ambient temperature       |                                     |     | -55 | 150 | °C   |
| T <sub>stg</sub> | storage temperature       |                                     |     | -65 | 150 | °C   |

<sup>[1]</sup> Total power dissipation junction to mounting base.

<sup>[2]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided 70 μm copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.

**Nexperia** 

#### 50 V, 2 A NPN high power bipolar transistor



FR4 PCB, single-sided 70 µm copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

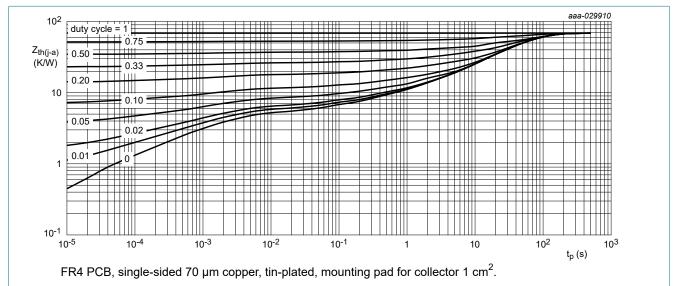
Fig. 1. **Power derating curves SOT428C** 

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

| Symbol                | Parameter   | Conditions  |     | Min | Тур | Max | Unit |
|-----------------------|---|-------------|-----|-----|-----|-----|------|
| R <sub>th(j-a)</sub>  | thermal resistance from junction to ambient       | in free air | [1] | -   | -   | 79  | K/W  |
| R <sub>th(j-mb)</sub> | thermal resistance from junction to mounting base |             |     | -   | -   | 9   | K/W  |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided 70 µm copper, tin-plated mounting pad for collector 1 cm<sup>2</sup>.



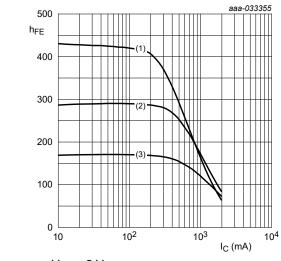
Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 50 V, 2 A NPN high power bipolar transistor

### 10. Characteristics

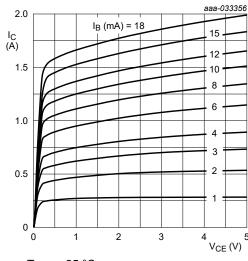
**Table 7. Characteristics** 

| Symbol             | Parameter                            | Conditions  | Mir | Тур | Max  | Unit |
|--------------------|--------------------------------------|---|-----|-----|------|------|
| I <sub>CES</sub>   | collector-emitter cut-off current    | V <sub>CE</sub> = 50 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C   | -   | -   | 100  | nA   |
| I <sub>EBO</sub>   | emitter-base cut-off current         | V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C   | -   | -   | 100  | nA   |
| h <sub>FE</sub>    | DC current gain                      | $V_{CE}$ = 2 V; $I_{C}$ = 0.5 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C                                | 120 | -   | 360  |      |
|                    |                                      | $V_{CE}$ = 2 V; $I_{C}$ = 2 A; pulsed; $t_{p} \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C                | 40  | -   | -    |      |
|                    |                                      | $V_{CE}$ = 1.6 V; $I_{C}$ = 0.75 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C                             | 80  | -   | 360  |      |
| V <sub>CEsat</sub> | collector-emitter saturation voltage | $I_C$ = 1 A; $I_B$ = 50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C                                     | -   | -   | 0.3  | V    |
| V <sub>BEsat</sub> | base-emitter saturation voltage      |   | -   | -   | 1.2  | V    |
| $V_{BE}$           | base-emitter voltage                 | $V_{CE}$ = 2 V; $I_{C}$ = 1 A; pulsed; $t_{p} \le 300 \ \mu s$ ; $T_{amb}$ = 25 °C                                    | -   | -   | 1.2  | V    |
|                    |                                      | $V_{CE}$ = 1.6 V; $I_{C}$ = 0.75 A; pulsed; $t_{p} \le$ 300 μs; $\delta \le$ 0.02; $T_{amb}$ = 25 °C                  | -   | -   | 0.95 | V    |
| C <sub>c</sub>     | collector capacitance                | $V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $<br>$T_{amb} = 25 ^{\circ}\text{C}$ | -   | -   | 80   | pF   |
| f <sub>T</sub>     | transition frequency                 | $V_{CE}$ = 10 V; $I_{C}$ = 100 mA; f = 100 MHz; $T_{amb}$ = 25 °C   | 65  | -   | -    | MHz  |



V<sub>CE</sub> = 2 V (1) T<sub>amb</sub> = 150 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -55 °C

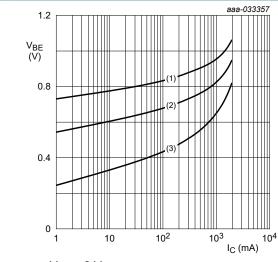
Fig. 3. DC current gain as a function of collector current; typical values



 $T_{amb}$  = 25 °C

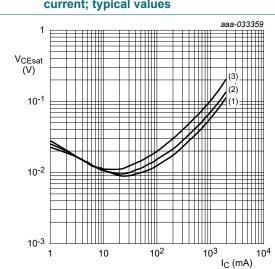
Fig. 4. Collector current as a function of collectoremitter voltage; typical values

#### 50 V, 2 A NPN high power bipolar transistor



V<sub>CE</sub> = 2 V (1) T<sub>amb</sub> = -55 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 150 °C

Fig. 5. Base-emitter voltage as a function of collector current; typical values

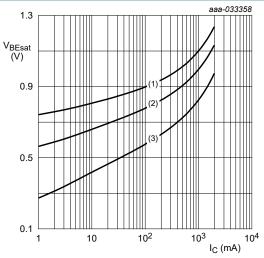


 $I_C/I_B = 20$ 

(1)  $T_{amb} = -55 \,^{\circ}C$ (2)  $T_{amb} = 25 \,^{\circ}C$ 

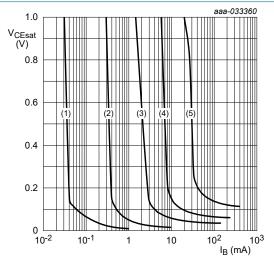
(3)  $T_{amb} = 150 \, ^{\circ}C$ 

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{C}/I_{B} = 20$ (1)  $T_{amb} = -55 \,^{\circ}C$ (2)  $T_{amb} = 25 \,^{\circ}C$ (3)  $T_{amb} = 150 \,^{\circ}C$ 

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



 $T_{amb}$  = 25 °C

(1)  $I_C = 0.01 A$ 

(2)  $I_C = 0.10 \text{ A}$ 

 $(3) I_C = 0.50 A$ 

 $(4) I_C = 1.00 A$ 

 $(5) I_C = 2.00 A$ 

Fig. 8. Collector-emitter saturation region as a function of base current; typical values

### 50 V, 2 A NPN high power bipolar transistor

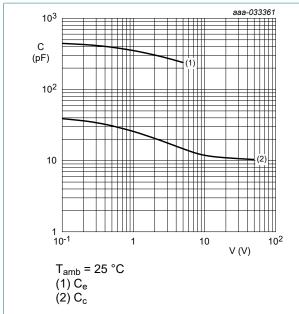


Fig. 9. Input/output capacitance as a function of input/output voltage

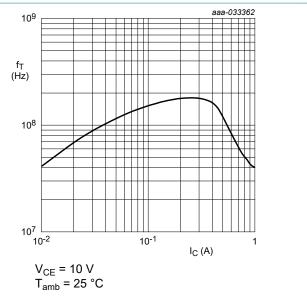
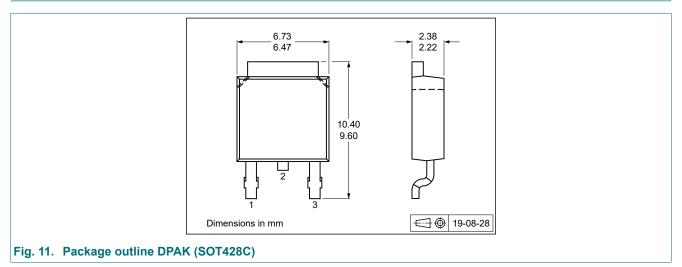


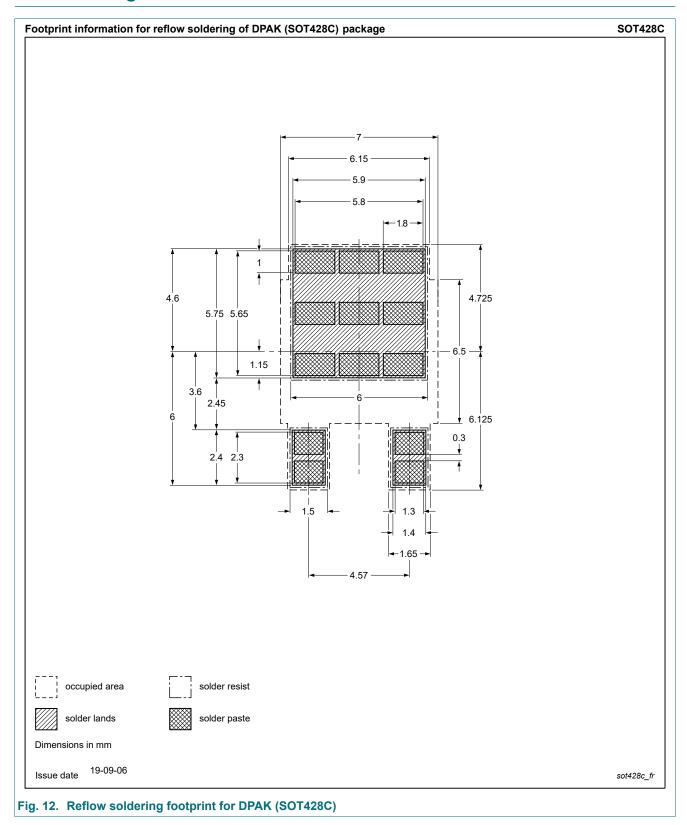
Fig. 10. Transition frequency as a function of collector current; typical values

# 11. Package outline



50 V, 2 A NPN high power bipolar transistor

# 12. Soldering



50 V, 2 A NPN high power bipolar transistor

# 13. Revision history

#### **Table 8. Revision history**

| Data sheet ID | Release date | Data sheet status  | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| MJD2873 v.1   | 20210426     | Product data sheet | -             | -          |

### 14. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

#### **Definitions**

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### **Disclaimers**

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

#### 50 V, 2 A NPN high power bipolar transistor

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nexperia.com/profile/terms">http://www.nexperia.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### **Trademarks**

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

MJD2873

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2021. All rights reserved

### 50 V, 2 A NPN high power bipolar transistor

### **Contents**

| 1.  | General description     | . 1 |
|-----|-------------------------|-----|
| 2.  | Features and benefits   | . 1 |
| 3.  | Applications            | . 1 |
| 4.  | Quick reference data    | . 1 |
| 5.  | Pinning information     | . 2 |
| 6.  | Ordering information    | . 2 |
| 7.  | Marking                 | . 2 |
| 8.  | Limiting values         | 2   |
| 9.  | Thermal characteristics | 3   |
| 10. | Characteristics         | . 4 |
| 11. | Package outline         | 6   |
| 12. | Soldering               | . 7 |
| 13. | Revision history        | .8  |
| 14. | Legal information       | .9  |
|     |                         |     |

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 26 April 2021

<sup>©</sup> Nexperia B.V. 2021. All rights reserved

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by Nexperia manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H BC546/116 BC557/116 BSW67A NTE158 NTE187A NTE195A NTE2302 NTE2330 NTE63 C4460
2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA2126-E 2SB1204S-TL-E 2SD2150T100R SP000011176 FMMTA92QTA 2N2369ADCSM
2N5769 2SC2412KT146S 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E
US6T6TR NJL0281DG 732314D CMXT3906 TR CPH3121-TL-E CPH6021-TL-H 873787E IMZ2AT108 UMX21NTR MCH6102-TL-E
FP204-TL-E NJL0302DG 2N3583 2SA1434-TB-E 2SC3143-4-TB-E 2SD1621S-TD-E NTE103 30A02MH-TL-E NSV40301MZ4T1G
NTE101 NTE13 NTE15